NSN 5961-01-258-5101

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view Online at https://aerobasegroup.com/nsn/5961-01-256-5101
Inclosure Material:
Metal
Overall Length:
1.573 inches
Terminal Length:
0.500 inches
Overall Height:
0.360 inches
Overall Width:
1.050 inches
Function For Which Designed:
Switching
Mounting Facility Quantity:
2
Internal Configuration:
Field effect
Mounting Method:
Unthreaded hole
Terminal Circle Diameter:
0.440 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 drain to source voltage and 400.0 drain to gate voltage
Current Rating Per Characteristic:
14.00 amperes drain current and 14.00 amperes detector signal current
Power Rating Per Characteristic:
150.0 watts total power dissipation
Maximum Operating Tempurature Per Measurement Point:
150.0 degrees celsius ambient air
Special Features:
Drain is electrically connected to the case
Test Data Document:
81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification
format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain
environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).
Terminal Type And Quantity:
2 pin and 1 case
Specification Data:
81349-mil-s-19500/543 government specification

N/a

Shelf Life:

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Demilitarization:

No

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